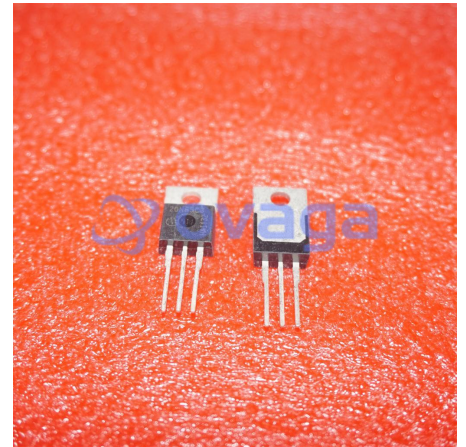


N-Channel MOSFETs (>500V...900V); Package: PG-TO220-3; VDS (max): 650.0 V;
 Package: TO-220; RDS(ON) @ TJ=25°C VGS=10: 190.0 mOhm; ID(max) @ TC=25°C:
 20.7 A; IDpuls (max): 62.1 A; MOSFET COOL MOS N-CH 650V 20.7

Manufacturers	Infineon Technologies Corporation
Package/Case	TO-220AB
Product Type	Transistors
RoHS	Rohs
Lifecycle	



Images are for reference only

Please submit RFQ for SPP20N65C3 or [Email to us: sales@ovaga.com](mailto:sales@ovaga.com) We will contact you in 12 hours.

[RFQ](#)

General Description

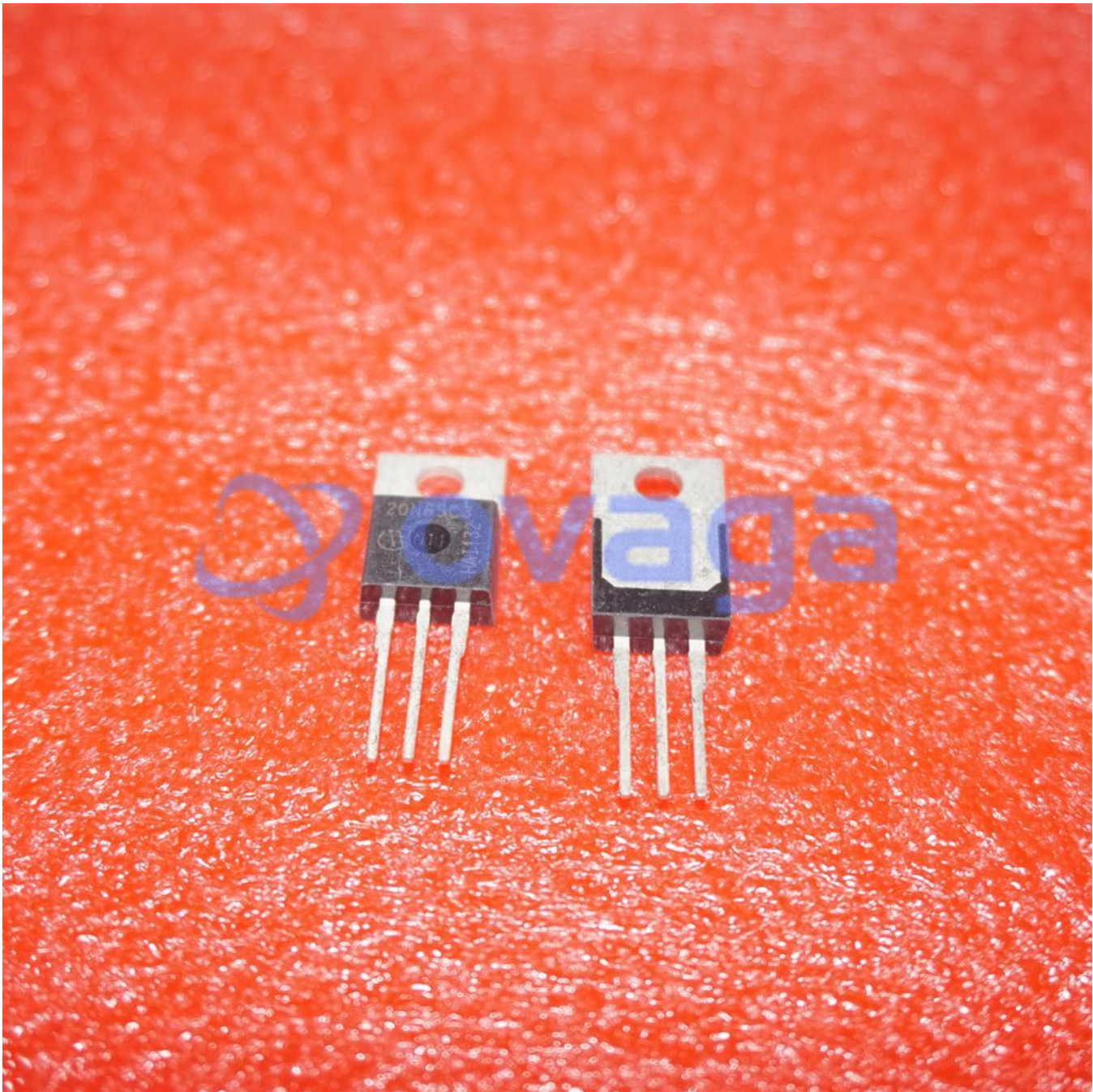
SPP20N65C3 is a power MOSFET transistor manufactured by Infineon Technologies. It belongs to the CoolMOS™ C3 series of high voltage superjunction MOSFETs.

Features

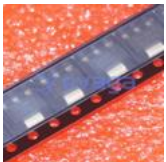
- Drain-Source Voltage (VDS): 650V
- Continuous Drain Current (ID): 20A
- Fast switching speed
- Low on-resistance
- High efficiency
- Avalanche-rated
- RoHS compliant

Application

- Switching power supplies
- Motor control
- Lighting
- Solar inverters
- Welding equipment
- Induction heating



Related Products



[BSP613P](#)

Infineon Technologies Corporation
SOT-223



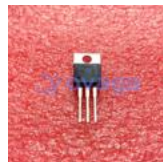
[SPP11N65C3](#)

Infineon Technologies Corporation
TO-220



[SPP07N65C3](#)

Infineon Technologies Corporation
TO-220AB



[SPP07N60S5](#)

Infineon Technologies Corporation
P-TO220-3-1



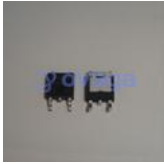
[SPP11N60C3XKSA1](#)

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PG-TO220



[IRF640NSPBF](#)

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PAK-3



[SPD03N60S5](#)

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TO-252



[SPP20N60CFD](#)

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TO-220AB